



- Intermediate Bus Architectures
- Distributed Power Architectures
- Data communications
- Telecommunications
- · Servers, workstations

Benefits

- High efficiency no heat sink required
- · Reduces total solution board area
- Tape and reel packing
- Compatible with pick &place equipment
- Minimizes part numbers in inventory
- Low cost

Member of the **Maxw** Family

Features

- RoHS lead free and lead-solder-exempted products are available
- Delivers up to 5 A (28 W)
- Extended input range 9.6 V 14 V
- No derating up to 85 °C (70 °C for 5V and 3.3V)
- Surface-mount package
- Industry-standard footprint and pinout
- Small size and low profile: 0.80" x 0.45" x 0.247" (20.32 x 11.43 x 6.27mm)
- Weight: 0.079 oz [2.26 g]
- Co-planarity < 0.003"
- Synchronous Buck Converter topology
- Start-up into pre-biased output
- No minimum load required
- Programmable output voltage via external resistor
- Operating ambient temperature: -40 °C to 85 °C
- Remote ON/OFF
- Fixed frequency operation
- Auto-reset output overcurrent protection
- Auto-reset overtemperature protection
- High reliability, MTBF approx. 71.8 Million Hours calculated per Telcordia TR-332, Method I Case 1
- All materials meet UL94, V-0 flammability rating
- UL 60950 recognition in U.S. & Canada, and DEMKO certification per IEC/EN 60950

Description

Power-One's point-of-load converters are recommended for use with regulated bus converters in an Intermediate Bus Architecture (IBA). The YM12S05 non-isolated DC-DC converters deliver up to 5A of output current in an industry-standard surface-mount package. Operating from a 9.6-14 VDC input, the YM12S05 converters are ideal choices for Intermediate Bus Architectures where Point-of-Load power (POL) delivery is generally a requirement. They provide an extremely tight regulated programmable output voltage of 0.7525 V to 5.5 V.

The Y-Series converters provide exceptional thermal performance, even in high temperature environments with minimal airflow. No derating is required up to 85 °C (up to 70 °C for 5 V and 3.3 V outputs), even without airflow at natural convection. This is accomplished through the use of advanced circuitry, packaging and processing techniques to achieve a design possessing ultra-high efficiency, excellent thermal management and a very low body profile.

The low body profile and the preclusion of heat sinks minimize impedance to system airflow, thus enhancing cooling for both upstream and downstream devices. The use of 100% automation for assembly, coupled with advanced power electronics and thermal design, results in a product with extremely high reliability.



Electrical Specifications

Conditions: T_A=25°C, Airflow=300 LFM (1.5 m/s), Vin=12VDC, Vout = 0.7525 - 5.5V, unless otherwise specified.

Parameter	Notes	Min	Тур	Max	Units	
Absolute Maximum Ratings						
Input Voltage	Continuous	-0.3		15	VDC	
Operating Ambient Temperature		-40		85	°C	
Storage Temperature		-55		125	°C	
Feature Characteristics						
Switching Frequency			310		kHz	
Output Voltage Trim Range ¹	By external resistor, See Trim Table 1	0.7525		5.5	VDC	
Turn-On Delay Time	Full resistive load					
With Vin = (Converter Enabled, then Vin applied)	From Vin = Vin(min) to Vo=0.1* Vo(nom)		7.5		ms	
With Enable (Vin = Vin(nom) applied, then enabled)	From enable to Vo= 0.1*Vo(nom)		7.5		ms	
Rise time (Full resistive load)	From 0.1*Vo(nom) to 0.9*Vo(nom)		7		ms	
ON/OFF Control ²						
Converter Off		2.4		Vin	VDC	
Converter On	_	-5		0.8	VDC	

Additional Notes:

- 1. The output voltage should not exceed 5.5V.
- 2. The converter is on if the ON/OFF pin is left open.



Electrical Specifications (continued)

Conditions: T_A =25°C, Airflow=300 LFM (1.5 m/s), Vin=12VDC, Vout = 0.7525 - 5.5V, unless otherwise specified.

Parameter	Notes	Min	Тур	Max	Units
Input Characteristics	•				
Operating Input Voltage Range		9.6	12	14	VDC
Input Under Voltage Lockout					
Turn-on Threshold			9.0		VDC
Turn-off Threshold			8.8		VDC
Maximum Input Current	5 ADC Out @ 9.6 VDC In				
	V _{OUT} = 5.0 VDC			2.9	ADC
	V _{OUT} = 3.3 VDC			2.0	ADC
	V _{OUT} = 2.5 VDC			1.6	ADC
	V _{OUT} = 2.0 VDC			1.4	ADC
	V _{OUT} = 1.8 VDC			1.25	ADC
	V _{OUT} = 1.5 VDC			1.0	ADC
	V _{OUT} = 1.2 VDC			0.8	ADC
	V _{OUT} = 1.0 VDC			0.7	ADC
Input Stand-by Current (Converter disabled)			1		mA
Input No Load Current (Converter enabled)	V _{OUT} = 5.0 VDC		65		mA
	V _{OUT} = 3.3 VDC		47		mA
	V _{OUT} = 2.5 VDC		35		mA
	V _{OUT} = 2.0 VDC		28		mA
	V _{OUT} = 1.8 VDC		25		mA
	V _{OUT} = 1.5 VDC		20		mA
	V _{OUT} = 1.2 VDC		17		mA
	V _{OUT} = 1.0 VDC		15		mA
Input Reflected-Ripple Current - is	See Fig. D for setup. (BW=20MHz)				
	V _{OUT} = 5.0 VDC		55		mA _{P-P}
	V _{OUT} = 3.3 VDC		48		mA _{P-P}
	V _{OUT} = 2.5 VDC		43		mA _{P-P}
	V _{OUT} = 2.0 VDC		38		mA _{P-P}
	V _{OUT} = 1.8 VDC		35		mA _{P-P}
	V _{OUT} = 1.5 VDC		32		mA _{P-P}
	V _{OUT} = 1.2 VDC		28		mA _{P-P}
	V _{OUT} = 1.0 VDC		25		mA _{P-P}
Input Voltage Ripple Rejection	120Hz		72		dB



Electrical Specifications (continued)

Conditions: T_A =25°C, Airflow=300 LFM (1.5 m/s), Vin=12VDC, Vout = 0.7525 - 5.5V, unless otherwise specified.

Parameter	Notes	Min	Тур	Max	Units
Output Characteristics					
Output Voltage Set Point (no load)		-1.5	Vout	+1.5	%Vout
Output Regulation ¹					
Over Line	Full resistive load		1		mV
Over Load	From no load to full load		0.25		%Vout
Output Voltage Range (Over all operating input voltage, resistive load and temperature conditions until end of life)		-2.5		+2.5	%Vout
Output Ripple and Noise - 20MHz bandwidth	Over line, load and temperature (Fig. D)				
Peak-to-Peak	V _{OUT} = 5.0 VDC		55	70	mV_{P-P}
Peak-to-Peak	V _{OUT} = 0.7525 VDC		40	50	mV_{P-P}
External Load Capacitance	Plus full load (resistive)				
Min ESR > 1mΩ				1,000	μF
Min ESR > 10 mΩ				2,000	μF
Output Current Range		0		5	Α
Output Current Limit Inception (I _{OUT})			10		Α
Output Short- Circuit Current	Short=10 mΩ, continuous		2		Arms
Dynamic Response					
lout step from 2.5A to 5A with di/dt = 5 A/µS	Co = 47 µF ceramic. + 1 µF ceramic		100		mV
Settling Time (V _{OUT} < 10% peak deviation)			20		μs
lout step from 5A to 2.5A with di/dt = -5 A/μS	Co = 47 µF ceramic + 1 µF ceramic		100		mV
Settling Time (V _{OUT} < 10% peak deviation)			20		μs
Efficiency	Full load (5A)				
	V _{OUT} = 5.0 VDC		92.0		%
	V _{OUT} = 3.3 VDC		88.5		%
	V _{OUT} = 2.5 VDC		86.5		%
	V _{OUT} = 2.0 VDC		84.5		%
	V _{OUT} = 1.8 VDC		83.5		%
	V _{OUT} = 1.5 VDC		81.5		%
	V _{OUT} = 1.2 VDC		79.0		%
	V _{OUT} = 1.0 VDC		76.0		%

Additional Notes:

1. Trim resistor connected across the GND and TRIM pins of the converter.



Operations

Input and Output Impedance

The Y-Series converter should be connected via a low impedance to the DC power source. In many applications, the inductance associated with the distribution from the power source to the input of the converter can affect the stability of the converter. It is recommended to use decoupling (minimum 47µF) placed as close as possible to the converter input pins in order to ensure stability of the converter and reduce input ripple voltage. Internally, the converter has 10µF (low ESR ceramics) of input capacitance.

In a typical application, low - ESR tantalum or POS capacitors will be sufficient to provide adequate ripple voltage filtering at the input of the converter. However, very low ESR ceramic capacitors 47µF- $100\mu F$ are recommended at the input of the converter in order to minimize the input ripple voltage. They should be placed as close as possible to the input pins of the converter.

The YM12S05 has been designed for stable operation with no external capacitance on the output. It is recommended to place low ESR ceramic capacitors to minimize output ripple voltage. Low ESR ceramic capacitors placed as close as possible to the load are recommended for improved transient performance and lower output voltage ripple.

It is important to keep low resistance and low inductance PCB traces for connecting your load to the output pins of the converter. This is required to maintain good load regulation since the converter does not have a SENSE pin for compensating voltage drops associated with the power distribution system on your PCB.

ON/OFF (Pin 1)

The ON/OFF pin (Pin 1) is used to turn the power converter on or off remotely via a system signal that is referenced to GND (Pin 4). The typical connections are shown in Fig. A.

To turn the converter on the ON/OFF pin should be at logic low or left open, and to turn the converter off the ON/OFF pin should be at logic high or connected to Vin.

The ON/OFF pin is internally pulled-down. A TTL or CMOS logic gate, open collector (open drain) transistor can be used to drive the ON/OFF pin. When using open collector (open drain) transistor,

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add a pull-up resistor (R*) of 75K to Vin as shown in Fig. A.

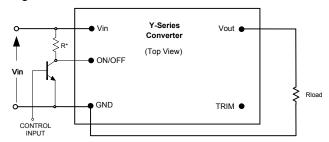


Fig. A: Circuit configuration for ON/OFF function.

This device must be capable of:

- sinking up to 0.2 mA at a low level voltage of $\leq 0.8 \text{ V}$
- sourcing up to 0.25 mA at a high logic level of 2.3V - 5V
- sourcing up to 0.75 mA when connected to Vin.

Output Voltage Programming (Pin 3)

The output voltage can be programmed from 0.7525V to 5.5V by connecting an external resistor between TRIM pin (Pin 3) and GND pin (Pin 4); see Fig. B. Note that when trim resistor is not connected, output voltage of the converter is 0.7525V.

A trim resistor, R_{TRIM}, for a desired output voltage can be calculated using the following equation:

$$R_{\text{TRIM}} = \frac{10.5}{\left(\text{Vo}_{\text{-REQ}} - 0.7525\right)} - 1 \hspace{1cm} [\text{k}\Omega]$$

where.

 $\mathbf{R}_{\mathsf{TRIM}} = \mathsf{Required}$ value of trim resistor [k Ω] **V**o-REQ = Desired (trimmed) output voltage [V]

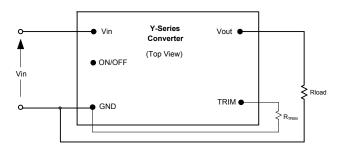


Fig. B: Configuration for programming output voltage.

Note that the tolerance of a trim resistor directly affects the output voltage tolerance. It is recommended to use standard 1% or 0.5% resistors; for tighter tolerance, two resistors in parallel are recommended rather than one standard value from Table 1.





Ground pin of the trim resistor should be connected directly to the converter GND pin with no voltage drop in between. Table 1 provides the trim resistor values for popular output voltages.

Table 1: Trim Resistor Value				
V _{0-REG} [V]	R _{TRIM} [kΩ]	The Closest Standard Value [kΩ]		
0.7525	open			
1.0	41.42	41.2		
1.2	22.46	22.6		
1.5	13.05	13.0		
1.8	9.02	9.09		
2.0	7.42	7.50		
2.5	5.01	4.99		
3.3	3.12	3.09		
5.0	1.47	1.47		
5.5	1.21	1.21		

The output voltage can be also programmed by external voltage source. To make trimming less sensitive, a series external resistor Rext is recommended between TRIM pin and programming voltage source. Control Voltage can be calculated by the formula:

$$V_{\text{CTRL}} = 0.7 - \frac{(1 + R_{\text{EXT}})(V_{\text{O-REQ}} - 0.7525)}{15}$$
 [V]

where

VCTRL = Control voltage [V]

 $\mathbf{R}_{\mathsf{EXT}} = \mathsf{External}$ resistor between TRIM pin and voltage source; the value can be chosen depending on the required output voltage range $[\mathsf{k}\Omega]$.

Control voltages with $\mathbf{R}_{\text{EXT}} = 0$ and $\mathbf{R}_{\text{EXT}} = 15K$ are shown in Table 2.

Table 2: Control Voltage [VDC]				
V _{0-REG} [V]	$V_{CTRL}(R_{EXT} = 0)$	$V_{CTRL}(R_{EXT} = 15K)$		
0.7525	0.700	0.700		
1.0	0.684	0.436		
1.2	0.670	0.223		
1.5	0.650	-0.097		
1.8	0.630	-0.417		
2.0	0.617	-0.631		
2.5	0.584	-1.164		
3.3	0.530	-2.017		
5.0	0.417	-3.831		
5.5	0.384	-4.364		

Protection Features

Input Undervoltage Lockout

Input undervoltage lockout is standard with this converter. The converter will shut down when the input voltage drops below a pre-determined voltage; it will start automatically when Vin returns to a specified range.

The input voltage must be typically 9.0V for the converter to turn on. Once the converter has been turned on, it will shut off when the input voltage drops below typically 8.8V.

Output Overcurrent Protection (OCP)

The converter is protected against overcurrent and short circuit conditions. Upon sensing an overcurrent condition, the converter will enter hiccup mode. Once over-load or short circuit condition is removed, Vout will return to nominal value.

Overtemperature Protection (OTP)

The converter will shut down under an overtemperature condition to protect itself from overheating caused by operation outside the thermal derating curves, or operation in abnormal conditions such as system fan failure. After the converter has cooled to a safe operating temperature, it will automatically restart.

Safety Requirements

The converter meets North American and International safety regulatory requirements per UL60950 and EN60950. The maximum DC voltage between any two pins is Vin under all operating conditions. Therefore, the unit has ELV (extra low voltage) output; it meets SELV requirements under the condition that all input voltages are ELV.

The converter is not internally fused. To comply with safety agencies requirements, a recognized fuse with a maximum rating of 7.5 Amps must be used in series with the input line.

Characterization

General Information

The converter has been characterized for many operational aspects, to include thermal derating (maximum load current as a function of ambient temperature and airflow) for vertical and horizontal mounting, efficiency, start-up and shutdown





parameters, output ripple and noise, transient response to load step-change, overload and short circuit.

The figures are numbered as Fig. x.y, where x indicates the different output voltages, and y associates with specific plots (y = 1 for the vertical thermal derating, ...). For example, Fig. x.1 will refer to the vertical thermal derating for all the output voltages in general.

The following pages contain specific plots or waveforms associated with the converter. Additional comments for specific data are provided below.

Test Conditions

All data presented were taken with the converter soldered to a test board, specifically a 0.060" thick printed wiring board (PWB) with four layers. The top and bottom layers were not metalized. The two inner layers, comprising two-ounce copper, were used to provide traces for connectivity to the converter.

The lack of metalization on the outer layers as well as the limited thermal connection ensured that heat transfer from the converter to the PWB was minimized. This provides a worst-case but consistent scenario for thermal derating purposes.

All measurements requiring airflow were made in the vertical and horizontal wind tunnel facilities using Infrared (IR) thermography and thermocouples for thermometry.

Ensuring components on the converter do not exceed their ratings is important to maintaining high reliability. If one anticipates operating the converter at or close to the maximum loads specified in the derating curves, it is prudent to check actual temperatures in the operating application. Thermographic imaging is preferable; if this capability is not available, then thermocouples may be used. . It is recommended the use of AWG #40 gauge thermocouples to ensure measurement accuracy. Careful routing of the thermocouple leads will further minimize measurement error. Refer to Fig. C for optimum measuring thermocouple locations.



Fig. C: Location of the thermocouple for thermal testing.

Thermal Derating

Load current vs. ambient temperature and airflow rates are given in Figs. x.1 to x.2 for maximum temperature of 120 °C. Ambient temperature was varied between 25 °C and 85 °C, with airflow rates from 30 to 500 LFM (0.15m/s to 2.5 m/s), and vertical and horizontal converter mounting.

For each set of conditions, the maximum load current is defined as the lowest of:

- (i) The output current at which any MOSFET temperature does not exceed a maximum specified temperature (120°C) as indicated by the thermographic image, or
- (ii) The maximum current rating of the converter (5A)

During normal operation, derating curves with maximum FET temperature less than or equal to 120 °C should not be exceeded. Temperature on the PCB at the thermocouple location shown in Fig. C should not exceed 120 °C in order to operate inside the derating curves.

Efficiency

Figure x.3 shows the efficiency vs. load current plot for ambient temperature of 25 °C, airflow rate of 200 LFM (1 m/s) and input voltages of 9.6V, 12V and 14V.

Power Dissipation

Fig. x.4 shows the power dissipation vs. load current plot for $Ta = 25^{\circ}C$, airflow rate of 200 LFM (1 m/s) with vertical mounting and input voltages of 9.6V, 12V and 14V.

Ripple and Noise

The output voltage ripple waveform is measured at full rated load current. Note that all output voltage waveforms are measured across a 1 μF ceramic capacitor.

The output voltage ripple and input reflected ripple current waveforms are obtained using the test setup shown in Fig. D.

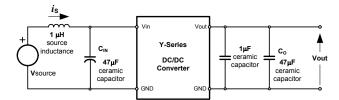


Fig. D: Test setup for measuring input reflected ripple currents, i_s and output voltage ripple.



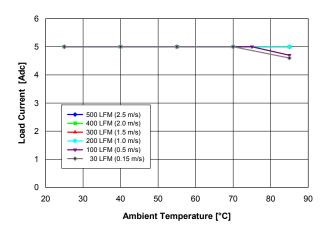


Fig. 5.0V.1: Available load current vs. ambient temperature and airflow rates for Vout = 5.0V converter mounted vertically with Vin = 12V, air flowing from pin 5 to pin 1 and maximum MOSFET temperature ≤ 120 °C.

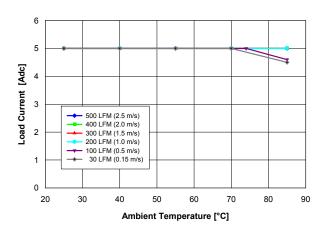


Fig. 5.0V.2: Available load current vs. ambient temperature and airflow rates for Vout = 5.0V converter mounted horizontally with Vin = 12V, air flowing from pin 5 to pin 1 and maximum MOSFET temperature ≤ 120 °C.

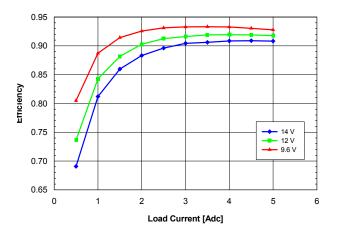


Fig. 5.0V.3: Efficiency vs. load current and input voltage for Vout = 5.0V converter mounted vertically with air flowing from pin 5 to pin 1 at a rate of 200 LFM (1 m/s) and Ta = 25 °C.

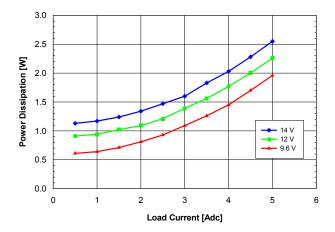


Fig. 5.0V.4: Power Loss vs. load current and input voltage for Vout = 5.0V converter mounted vertically with air flowing from pin 5 to pin 1 at a rate of 200 LFM (1 m/s) and Ta = 25 °C.

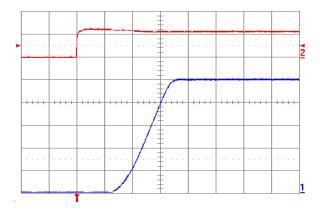


Fig. 5.0V.5: Turn-on transient for Vout = 5.0V with application of Vin at full rated load current (resistive) and $47\mu F$ external capacitance at Vin = 12V. Top trace: Vin (10V/div.); Bottom trace: output voltage (1V/div.); Time scale: 5 ms/div.

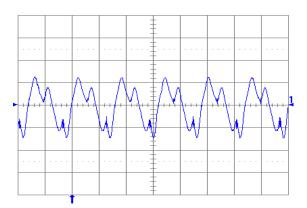


Fig. 5.0V.6: Output voltage ripple (10mV/div.) at full rated load current into a resistive load with external capacitance $47\mu F$ ceramic + $1\mu F$ ceramic and Vin = 12V for Vout = 5.0V. Time scale: $2 \mu s/div$.

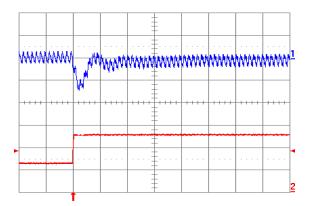


Fig. 5.0V.7: Output voltage response for Vout = 5.0V to positive load current step change from 2.5A to 5A with slew rate of $5A/\mu s$ at Vin = 12V. Top trace: output voltage (100mV/div.); Bottom trace: load current (2A/div.). Co = $47\mu F$ ceramic. Time scale: $20\mu s/div$.

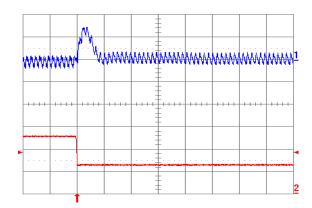


Fig. 5.0V.8: Output voltage response for Vout = 5.0V to negative load current step change from 5A to 2.5A with slew rate of -5A/ μ s at Vin = 12V. Top trace: output voltage (100mV/div.); Bottom trace: load current (2A/div.). Co = 47 μ F ceramic. Time scale: 20 μ s/div.

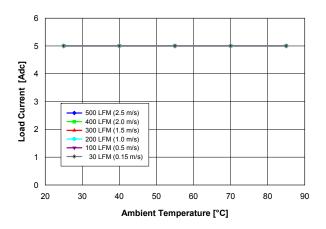


Fig. 3.3V.1: Available load current vs. ambient temperature and airflow rates for Vout = 3.3V converter mounted vertically with Vin = 12V, air flowing from pin 5 to pin 1 and maximum MOSFET temperature ≤ 120 °C.

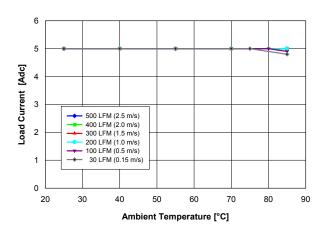


Fig. 3.3V.2: Available load current vs. ambient temperature and airflow rates for Vout = 3.3V converter mounted horizontally with Vin = 12V, air flowing from pin 5 to pin 1 and maximum MOSFET temperature \leq 120 °C.

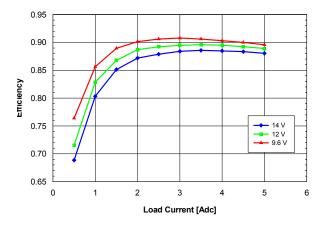


Fig. 3.3V.3: Efficiency vs. load current and input voltage for Vout = 3.3V converter mounted vertically with air flowing from pin 5 to pin 1 at a rate of 200 LFM (1 m/s) and Ta = 25 °C.

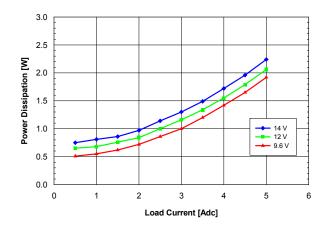


Fig. 3.3V.4: Power Loss vs. load current and input voltage for Vout = 3.3V converter mounted vertically with air flowing from pin 5 to pin 1 at a rate of 200 LFM (1 m/s) and Ta = 25 °C.

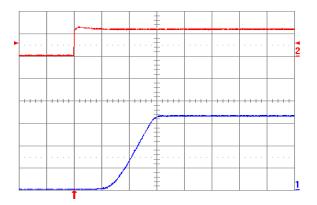


Fig. 3.3V.5: Turn-on transient for Vout = 3.3V with application of Vin = 12V at full rated load current (resistive) and 47μ F external capacitance. Top trace: Vin (10V/div); Bottom trace: Vout (1V/div); Time scale: 2 ms/div.

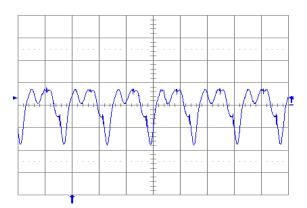


Fig. 3.3V.6: Output voltage ripple (10mv/div) at full rated load current into a resistive load with external capacitance $47\mu\text{F}$ ceramic + $1\mu\text{F}$ ceramic and Vin = 12V for Vout = 3.3V. Time scale: 2 $\mu\text{s}/\text{div}$.

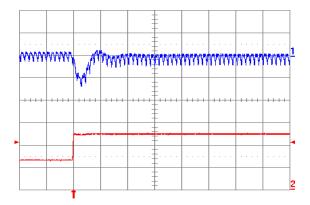


Fig. 3.3V.7: Output voltage response for Vout = 3.3V to a positive load current step change from 2.5A to 5A with a slew rate of 5A/ μ s at Vin = 12V. Top trace: output voltage (100mv/div); Bottom trace: load current (2A/div). Co = 47 μ F ceramic. Time scale: 20 μ s/div.

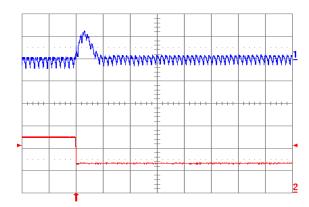


Fig. 3.3V.8: Output voltage response for Vout = 3.3V to a negative load current step change from 5A to 2.5A with a slew rate of -5A/ μ s at Vin = 12V. Top trace: output voltage (100mv/div); Bottom trace: load current (2A/div). Co = 47 μ F ceramic. Time scale: 20 μ s/div.

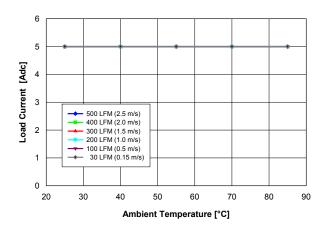


Fig. 2.5V.1: Available load current vs. ambient temperature and airflow rates for Vout = 2.5V converter mounted vertically with Vin = 12V, air flowing from pin 5 to pin 1 and maximum MOSFET temperature ≤ 120 °C.

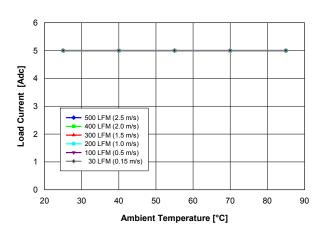


Fig. 2.5V.2: Available load current vs. ambient temperature and airflow rates for Vout = 2.5V converter mounted horizontally with Vin = 12V, air flowing from pin 5 to pin 1 and maximum MOSFET temperature $\leq 120^{\circ}C$.

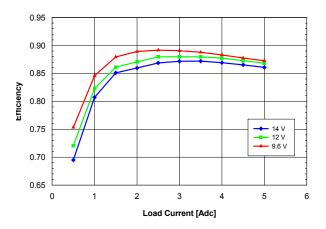


Fig. 2.5V.3: Efficiency vs. load current and input voltage for Vout = 2.5V converter mounted vertically with air flowing from pin 5 to pin 1 at a rate of 200 LFM (1 m/s) and Ta = 25 °C.

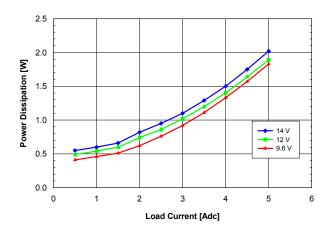


Fig. 2.5V.4: Power Loss vs. load current and input voltage for Vout = 2.5V converter mounted vertically with air flowing from pin 5 to pin 1 at a rate of 200 LFM (1 m/s) and Ta = 25 °C.

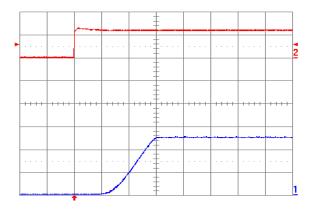


Fig. 2.5V.4: Turn-on transient for Vout = 2.5V with application of Vin = 12V at full rated load current (resistive) and $47\mu\text{F}$ external capacitance. Top trace: Vin (10V/div); Bottom trace: Vout (1V/div); Time scale: 2 ms/div.

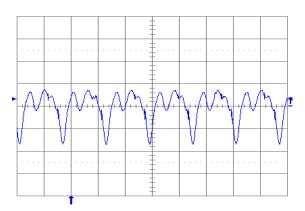


Fig. 2.5V.5: Output voltage ripple (10mv/div) at full rated load current into a resistive load with external capacitance $47\mu\text{F}$ ceramic + $1\mu\text{F}$ ceramic and Vin = 12V for Vout = 2.5V. Time scale: $2\,\mu\text{s}/\text{div}$.

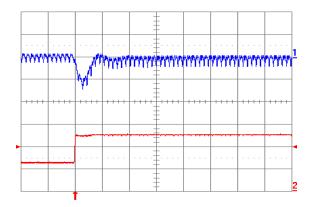


Fig. 2.5V.7: Output voltage response for Vout = 2.5V to a positive load current step change from 2.5A to 5A with a slew rate of 5A/ μ s at Vin = 12V. Top trace: output voltage (100mv/div); Bottom trace: load current (2A/div). Co = 47 μ F ceramic. Time scale: 20 μ s/div.

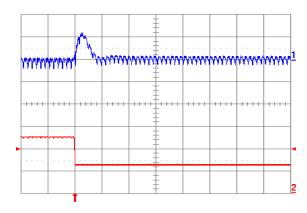


Fig. 2.5V.8: Output voltage response for Vout = 2.5V to a negative load current step change from 5A to 2.5A with a slew rate of -5A/ μ s at Vin = 12V. Top trace: output voltage (100mv/div); Bottom trace: load current (2A/div). Co = 47 μ F ceramic. Time scale: 20 μ s/div.

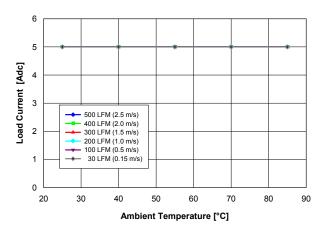


Fig. 2.0V.1: Available load current vs. ambient temperature and airflow rates for Vout = 2.0V converter mounted vertically with Vin = 12V, air flowing from pin 5 to pin 1 and maximum MOSFET temperature ≤ 120 °C.

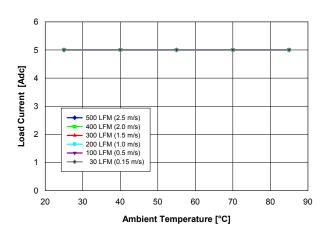


Fig. 2.0V.2: Available load current vs. ambient temperature and airflow rates for Vout = 2.0V converter mounted horizontally with Vin = 12V, air flowing from pin 5 to pin 1 and maximum MOSFET temperature \leq 120 °C.

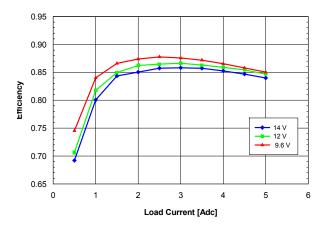


Fig. 2.0V.3: Efficiency vs. load current and input voltage for Vout = 2.0V converter mounted vertically with air flowing from pin 5 to pin 1 at a rate of 200 LFM (1 m/s) and Ta = 25 °C.

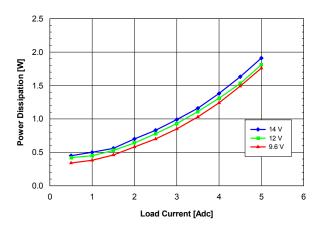


Fig. 2.0V.4: Power Loss vs. load current and input voltage for Vout = 2.0V converter mounted vertically with air flowing from pin 5 to pin 1 at a rate of 200 LFM (1 m/s) and Ta = 25 °C.

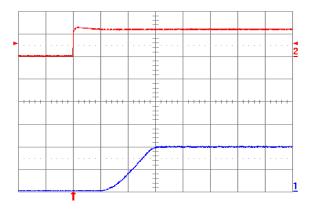


Fig. 2.0V.5: Turn-on transient for Vout = 2.0V with application of Vin = 12V at full rated load current (resistive) and $47\mu F$ external capacitance. Top trace: Vin (10V/div); Bottom trace: Vout (1V/div); Time scale: 2 ms/div.

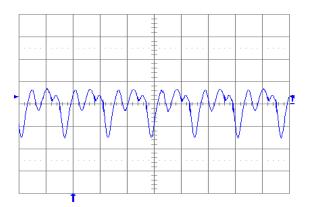


Fig. 2.0V.6: Output voltage ripple (10mv/div) at full rated load current into a resistive load with external capacitance $47\mu\text{F}$ ceramic + $1\mu\text{F}$ ceramic and Vin = 12V for Vout = 2.0V. Time scale: $2\,\mu\text{s}/\text{div}$.

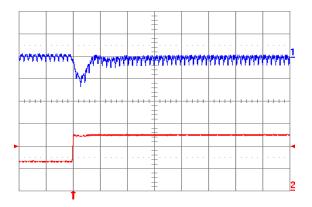


Fig. 2.0V.7: Output voltage response for Vout = 2.0V to a positive load current step change from 2.5A to 5A with a slew rate of $5A/\mu s$ at Vin = 12V. Top trace: output voltage (100mv/div); Bottom trace: load current (2A/div). Co = $47\mu F$ ceramic. Time scale: 20 $\mu s/div$.

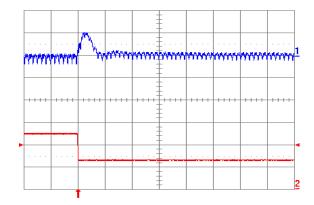


Fig. 2.0V.8: Output voltage response for Vout = 2.0V to a negative load current step change from 5A to 2.5A with a slew rate of -5A/ μ s at Vin = 12V. Top trace: output voltage (100mv/div); Bottom trace: load current (2A/div). Co = 47 μ F ceramic. Time scale: 20 μ s/div.

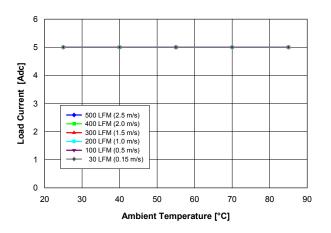


Fig. 1.8V.1: Available load current vs. ambient temperature and airflow rates for Vout = 1.8V converter mounted vertically with Vin = 12V, air flowing from pin 5 to pin 1 and maximum MOSFET temperature \leq 120 °C.

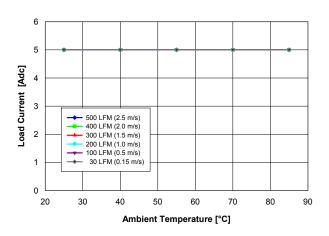


Fig. 1.8V.2: Available load current vs. ambient temperature and airflow rates for Vout = 1.8V converter mounted horizontally with Vin = 12V, air flowing from pin 5 to pin 1 and maximum MOSFET temperature ≤ 120 °C.

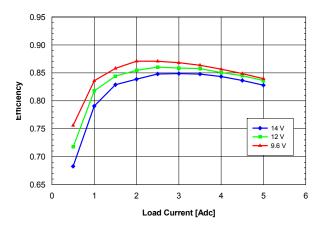


Fig. 1.8V.3: Efficiency vs. load current and input voltage for Vout = 1.8V converter mounted vertically with air flowing from pin 5 to pin 1 at a rate of 200 LFM (1 m/s) and Ta = 25 °C.

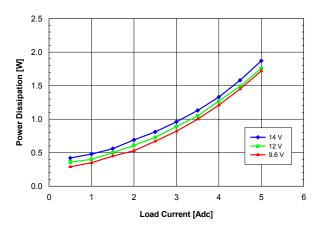


Fig. 1.8V.4: Power Loss vs. load current and input voltage for Vout = 1.8V converter mounted vertically with air flowing from pin 5 to pin 1 at a rate of 200 LFM (1 m/s) and Ta = 25 °C.

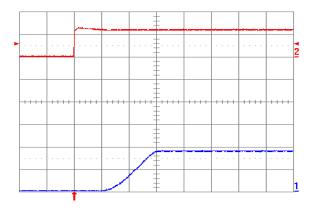


Fig. 1.8V.5: Turn-on transient for Vout = 1.8V with application of Vin = 12V at full rated load current (resistive) and 47μ F external capacitance. Top trace: Vin (10V/div); Bottom trace: Vout (1V/div); Time scale: 2 ms/div.

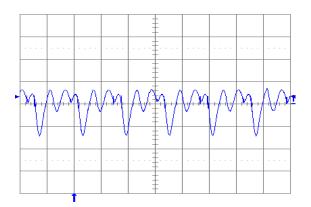


Fig. 1.8V.6: Output voltage ripple (10mv/div) at full rated load current into a resistive load with external capacitance $47\mu F$ ceramic + $1\mu F$ ceramic and Vin = 12V for Vout = 1.8V. Time scale: $2 \mu s/div$.

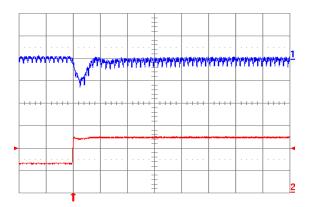


Fig. 1.8V.7: Output voltage response for Vout = 1.8V to a positive load current step change from 2.5A to 5A with a slew rate of $5A/\mu s$ at Vin = 12V. Top trace: output voltage (100mv/div); Bottom trace: load current (2A/div). Co = $47\mu F$ ceramic. Time scale: 20 $\mu s/div$.

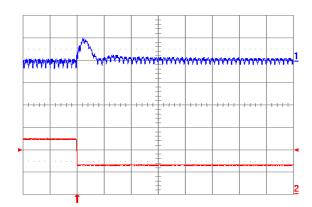


Fig. 1.8V.8: Output voltage response for Vout = 1.8V to a negative load current step change from 5A to 2.5A with a slew rate of -5A/ μ s at Vin = 12V. Top trace: output voltage (100mv/div); Bottom trace: load current (2A/div). Co = 47 μ F ceramic. Time scale: 20 μ s/div.

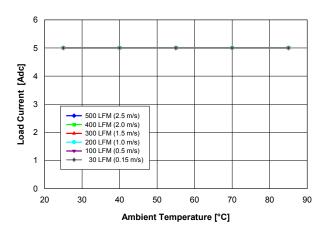


Fig. 1.5V.1: Available load current vs. ambient temperature and airflow rates for Vout = 1.5V converter mounted vertically with Vin = 12V, air flowing from pin 5 to pin 1 and maximum MOSFET temperature \leq 120 °C.

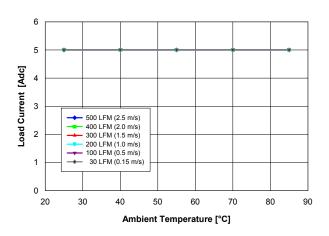


Fig. 1.5V.2: Available load current vs. ambient temperature and airflow rates for Vout = 1.5V converter mounted horizontally with Vin = 12V, air flowing from pin 5 to pin 1 and maximum MOSFET temperature ≤ 120 °C.

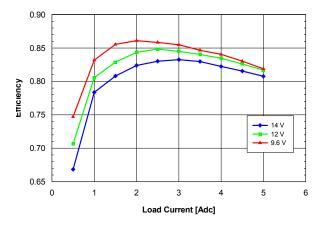


Fig. 1.5V.3: Efficiency vs. load current and input voltage for Vout = 1.5V converter mounted vertically with air flowing from pin 5 to pin 1 at a rate of 200 LFM (1 m/s) and Ta = 25 °C.

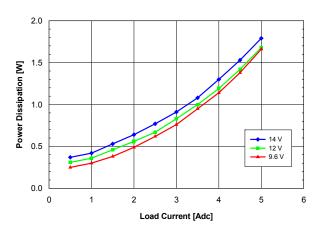


Fig. 1.5V.4: Power Loss vs. load current and input voltage for Vout = 1.5V converter mounted vertically with air flowing from pin 5 to pin 1 at a rate of 200 LFM (1 m/s) and Ta = 25 °C.

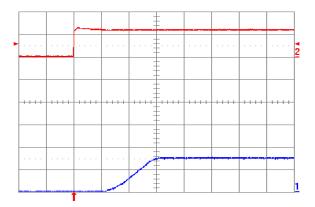


Fig. 1.5V.5: Turn-on transient for Vout = 1.5V with application of Vin = 12V at full rated load current (resistive) and 47μ F external capacitance. Top trace: Vin (10V/div); Bottom trace: Vout (1V/div); Time scale: 2 ms/div.

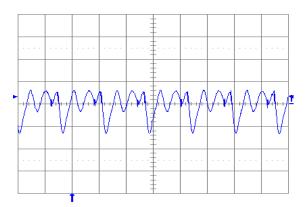


Fig. 1.5V.6: Output voltage ripple (10mv/div) at full rated load current into a resistive load with external capacitance $47\mu\text{F}$ ceramic + $1\mu\text{F}$ ceramic and Vin = 12V for Vout = 1.5V. Time scale: $2 \mu\text{s/div}$.

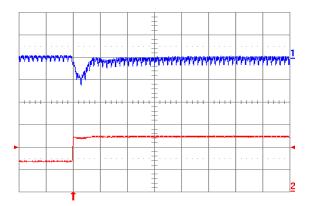


Fig. 1.5V.7: Output voltage response for Vout = 1.5V to a positive load current step change from 2.5A to 5A with a slew rate of $5A/\mu s$ at Vin = 12V. Top trace: output voltage (100mv/div); Bottom trace: load current (2A/div). Co = $47\mu F$ ceramic. Time scale: 20 $\mu s/div$.

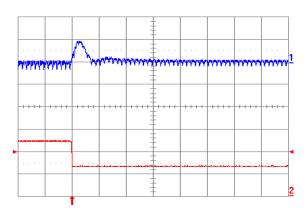


Fig. 1.5V.8: Output voltage response for Vout = 1.5V to a negative load current step change from 5A to 2.5A with a slew rate of -5A/ μ s at Vin = 12V. Top trace: output voltage (100mv/div); Bottom trace: load current (2A/div). Co = 47 μ F ceramic. Time scale: 20 μ s/div.

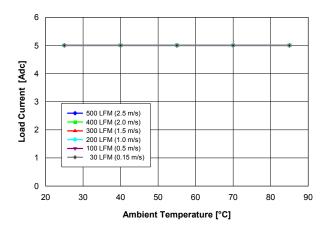


Fig. 1.2V.1: Available load current vs. temperature and airflow rates for Vout = 1.2V converter mounted vertically with Vin = 12V, air flowing from pin 5 to pin 1 and maximum MOSFET temperature ≤ 120 °C.

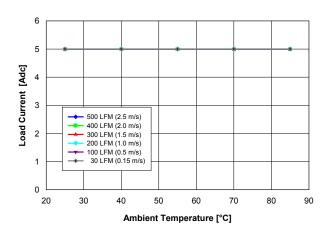


Fig. 1.2V.2: Available load current vs. ambient temperature and airflow rates for Vout = 1.2V converter mounted horizontally with Vin = 12V, air flowing from pin 5 to pin 1 and maximum MOSFET temperature ≤ 120 °C.

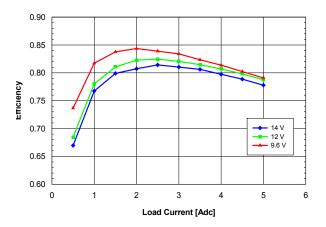


Fig. 1.2V.3: Efficiency vs. load current and input voltage for Vout = 1.2V converter mounted vertically with air flowing from pin 5 to pin 1 at a rate of 200 LFM (1 m/s) and Ta = 25 °C.

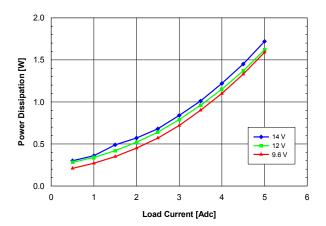


Fig. 1.2V.4: Power Loss vs. load current and input voltage for Vout = 1.2V converter mounted vertically with air flowing from pin 5 to pin 1 at a rate of 200 LFM (1 m/s) and Ta = 25 °C.

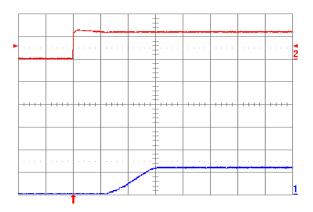


Fig. 1.2V.5: Turn-on transient for Vout = 1.2V with application of Vin = 12V at full rated load current (resistive) and $47\mu\text{F}$ external capacitance. Top trace: Vin (10V/div); Bottom trace: Vout (1V/div); Time scale: 2 ms/div.

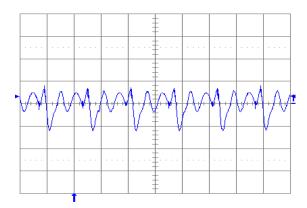


Fig. 1.2V.6: Output voltage ripple (10mv/div) at full rated load current into a resistive load with external capacitance $47\mu\text{F}$ ceramic + $1\mu\text{F}$ ceramic and Vin = 12V for Vout = 1.2V. Time scale: $2 \mu\text{s}/\text{div}$.

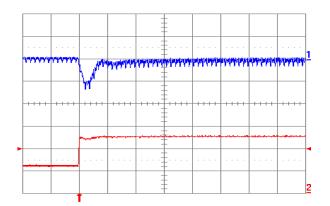


Fig. 1.2V.6: Output voltage response for Vout = 1.2V to a positive load current step change from 2.5A to 5A with a slew rate of $5A/\mu s$ at Vin = 12V. Top trace: output voltage (100mv/div); Bottom trace: load current (2A/div). Co = $47\mu F$ ceramic. Time scale: 20 $\mu s/div$.

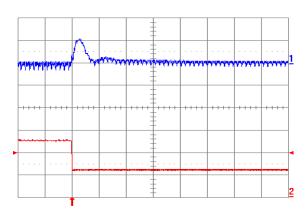


Fig. 1.2V.8: Output voltage response for Vout = 1.2V to a negative load current step change from 5A to 2.5A with a slew rate of 5A/ μ s at Vin = 12V. Top trace: output voltage (100mv/div); Bottom trace: load current (2A/div). Co = 47 μ F ceramic. Time scale: 20 μ s/div.

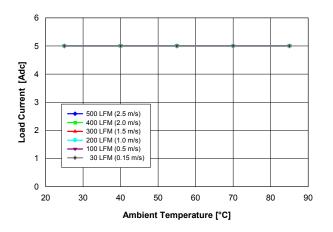


Fig. 1.0V.1: Available load current vs. temperature and airflow rates for Vout = 1.0V converter mounted vertically with Vin = 12V, air flowing from pin 5 to pin 1 and maximum MOSFET temperature ≤ 120 °C.

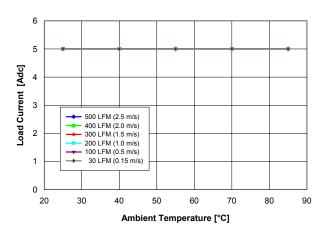


Fig. 1.0V.2: Available load current vs. ambient temperature and airflow rates for Vout = 1.0V converter mounted horizontally with Vin = 12V, air flowing from pin 5 to pin 1 and maximum MOSFET temperature ≤ 120 °C.

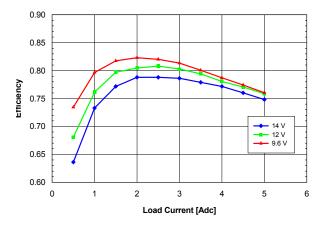


Fig. 1.0V.3: Efficiency vs. load current and input voltage for Vout = 1.0V converter mounted vertically with air flowing from pin 5 to pin 1 at a rate of 200 LFM (1 m/s) and Ta = 25 °C.

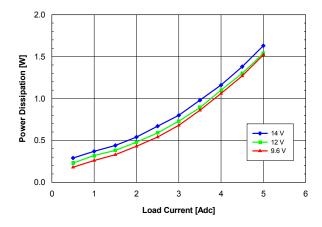


Fig. 1.0V.4: Power Loss vs. load current and input voltage for Vout = 1.0V converter mounted vertically with air flowing from pin 5 to pin 1 at a rate of 200 LFM (1 m/s) and Ta = 25 °C.

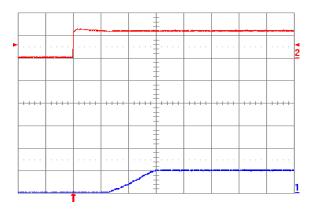


Fig. 1.0V.5: Turn-on transient for Vout = 1.0V with application of Vin = 12V at full rated load current (resistive) and 47µF external capacitance. Top trace: Vin (10V/div); Bottom trace: Vout (1V/div); Time scale: 2 ms/div.

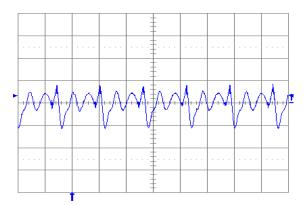


Fig. 1.0V.6: Output voltage ripple (10mv/div) at full rated load current into a resistive load with external capacitance $47\mu F$ ceramic + $1\mu F$ ceramic and Vin = 12V for Vout = 1.0V. Time scale: 2 µs/div.

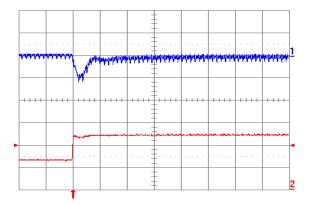


Fig. 1.0V.7: Output voltage response for Vout = 1.0V to a positive load current step change from 2.5A to 5A with a slew rate of 5A/µs at Vin = 12V. Top trace: output voltage (100mv/div); Bottom trace: load current (2A/div). Co = 47μF ceramic. Time scale: 20 μs/div.

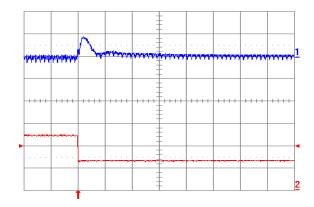
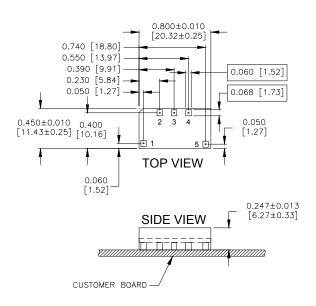


Fig. 1.0V.8: Output voltage response for Vout = 1.0V to a negative load current step change from 5A to 2.5A with a slew rate of 5A/µs at Vin = 12V. Top trace: output voltage (100mv/div); Bottom trace: load current (2A/div). Co = 47µF ceramic. Time scale: 20 µs/div.



Physical Information



YM12S Pinout (Surface Mount)

Pad/Pin Connections			
Pad/Pin # Function			
1	ON/OFF		
2	Vout		
3	TRIM		
4	GND		
5	Vin		

YM12S Platform Notes

- All dimensions are in inches [mm]
- Connector Material: Copper
- Connector Finish: Gold over Nickel
- Module Weight: 0.079 oz [2.26 g]
- Module Height: 0.260" Max., 0.234" Min.
- Recommended Surface-Mount Pads: Min. 0.080" X 0.112" [2.03 x 2.84]

Converter Part Numbering Scheme

Product Series	Input Voltage	Mounting Scheme	Rated Load Current	RoHS Compatible
YM	12	S	05	G
Y-Series	9.6V – 14V	S ⇒ Surface Mount	5A (0.7525V to 5.5V)	No Suffix \Rightarrow RoHS lead-solder-exempt compliant $G \Rightarrow$ RoHS Compliant

The example above describes P/N YM12S05G: 9.6V – 14V input, surface mount, 5A at 0.7525V to 5.5V output, and RoHS compliant. Please consult factory regarding availability of a specific version.

NUCLEAR AND MEDICAL APPLICATIONS - Power-One products are not designed, intended for use in, or authorized for use as critical components in life support systems, equipment used in hazardous environments, or nuclear control systems without the express written consent of the respective divisional president of Power-One, Inc.

TECHNICAL REVISIONS - The appearance of products, including safety agency certifications pictured on labels, may change depending on the date manufactured. Specifications are subject to change without notice.

